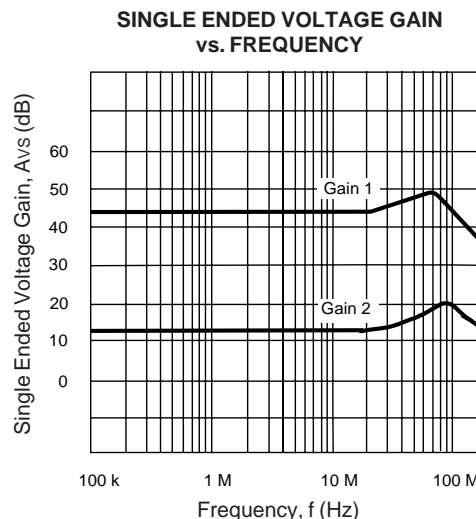


FEATURES

- **BANDWIDTH AND TYPICAL GAIN**
120 MHz at $A_{VOL} = 300$
170 MHz at $A_{VOL} = 100$
700 MHz at $A_{VOL} = 10$
- **VERY SMALL PHASE DELAY**
- **GAIN ADJUSTABLE FROM 10 TO 300**
- **NO FREQUENCY COMPENSATION REQUIRED**

DESCRIPTION

The UPC1663G and GV are video amplifiers with differential input and output stages. A high frequency process ($f_T = 6$ GHz) improves AC performance compared with industry-standard video amplifiers. These devices are excellent as sense amplifiers for high-density CCDs, as video or pulse amplifiers in high-resolution displays, and in communications equipment.



ELECTRICAL CHARACTERISTICS (TA = 25°C, VCC = ±6 V, RS = 50 Ω, f = 500 MHz)

PART NUMBER PACKAGE OUTLINE			UPC1663G, GV G08, S08		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX
I _{CC}	Power Supply Current	mA		13	20
A _v d	Differential Voltage Gain: Gain ¹ Gain ²		200 8	320 10	500 12
BW	Bandwidth (Gain is 3 dB down from the gain at 100 KHz)	MHz		120	
t _R	Rise Time, V _{OUT} = 1V _{p-p} :	ns		2.9	
t _{pd}	Propagation Delay, V _{OUT} = 1 V _{p-p} :	ns		2.7	
R _{IN}	Input Impedance:	kΩ		2	
C _{IN}	Input Capacitance	pF		1.2	
I _{IO}	Input Offset Current	μA		4.0	5.0
I _B	Input Bias Current	μA		180	40
V _N	Input Noise Voltage, 10 k to 10 MHz	μV _{r.m.s.}		3	
V _I	Input Voltage Range	V	±1.0		
CMRR	Common Mode Rejection Ratio, V _{cm} = ±1 V, f ≤ 100 kHz	dB	55	70	
	V _{cm} = ±1 V, f = 5 MHz	dB	53	60	
SVRR	Supply Voltage Rejection Ratio, ΔV = ±0.5 V	dB	50	70	
V _{O(off)}	Output Offset Voltage, V _{O(off)} = OUT1 - OUT2	V		0.3	1.5
	Gain ¹	V		0.1	1.0
	Gain ²	V			
V _{O(CM)}	Output Common Mode Voltage	V	2.4	2.9	3.4
V _{Op-p}	Max. Output Voltage Swing	V _{p-p}	3.0	4.0	
I _{sink}	Output Sink Current	mA	2.5	3.6	

Notes:

1. Gain select pins GA and GB are connected together.
2. All gain select pins are open.
3. Insert adjustment resistor (0 to 10 kΩ) between GA and GB when variable gain is necessary.

ABSOLUTE MAXIMUM RATINGS¹ (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V _C -V _E	Voltage between V _C and V _E UPC1663G, GV	V	-0.3 to 14
P _T	Total Power Dissipation UPC1663G ² UPC1663GV ³	mW mW	280 200
V _{ID}	Differential Input Voltage	V	±5
V _{IN}	Input Voltage	V	±6
I _O	Output Current	mA	35
T _{OP}	Operating Temperature UPC1663G, UPC1663GV	°C	-45 to +75
T _{STG}	Storage Temperature	°C	-55 to +150

Notes:

1. Operation in excess of any one of these parameters may result in permanent damage.
2. Mounted on 5 cm x 5 cm x 0.16 mm glass epoxy PCB (T_A = Max T_{OP}).
3. Mounted on 50 cm x 50 cm x 1.6 mm glass epoxy PCB with copper film (T_A = Max T_{OP}).

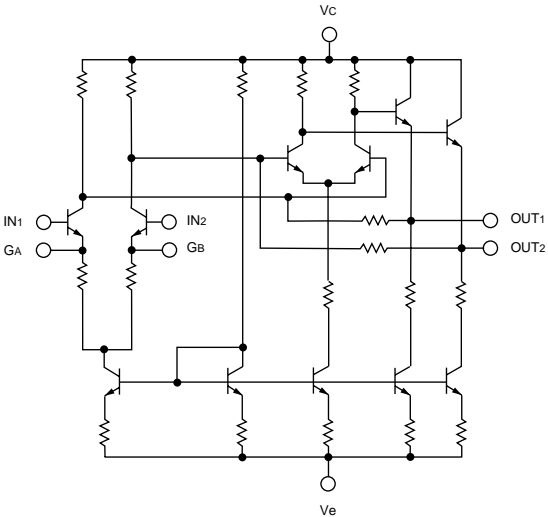
RECOMMENDED
OPERATING CONDITIONS (T_A = 25°C)

SYMBOLS	CHARACTERISTICS	UNITS	MIN	TYP	MAX
V _C (1663G, GV)	Positive Supply Voltage	V	+2	+6	+6.5
V _E (1663G, GV)	Negative Supply Voltage	V	-2	-6	-6.5
I _O source	Source Current	mA			20
I _O sink	Sink Current	mA			2.5
	Frequency Range	MHz	DC		200

Attention:

Due to high frequency characteristics, the physical circuit layout is very critical. Supply voltage line bypass, double-sided printed-circuit board, and wide-area ground line layout are necessary for stable operation. Two signal resistors connected to both inputs and two load resistors connected to both outputs should be balanced for stable operation.

EQUIVALENT CIRCUIT

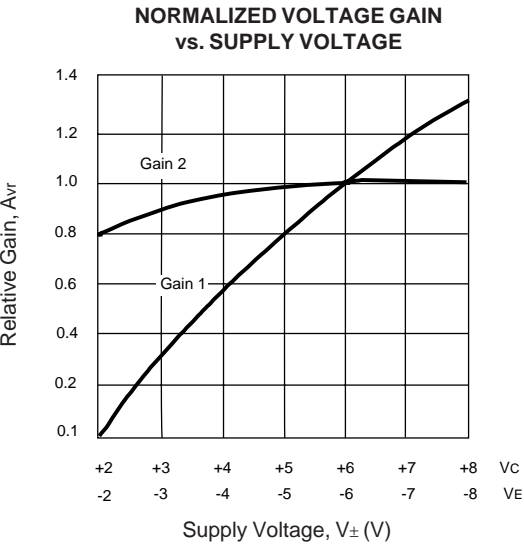
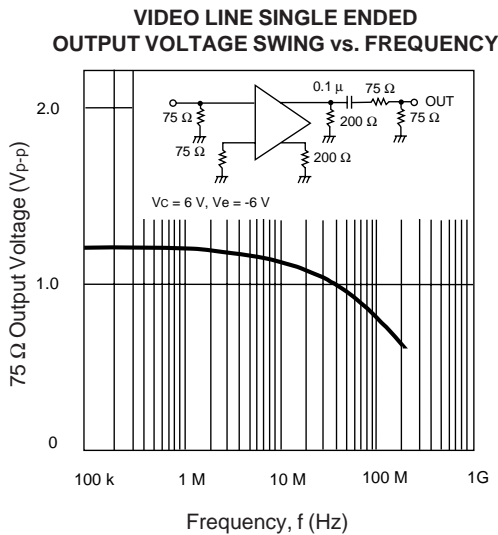


TYPICAL PERFORMANCE UNDER
SINGLE SUPPLY +5 V OPERATION*

PARAMETER	CONDITIONS	TYPICAL	UNITS
Differential Gain Gain 1 Gain 2	15 MHz	35 11	dB dB
Bandwidth Gain 1 Gain 2	Gain is 3 dB down from the gain at 100 KHz	106 115	MHz MHz
Rise Time Gain 1	R _S = 50 Ω, V _{OUT} = 80 mV _{p-p}	2.2	ns
Propagation Delay Gain 1 Gain 2	R _S = 50 Ω, V _{OUT} = 80 mV _{p-p} R _S = 50 Ω, V _{OUT} = 60 mV _{p-p}	2.8 1.8	ns ns
Phase Shift Gain 1 Gain 2	100 MHz	-123 -93	degree degree
Output Power R _A = 240 Ω R _A = 910 Ω R _A = 80 Ω	Z _L = 50 Ω, 15 MHz	5.0 0 -11.5	dBm dBm dBm

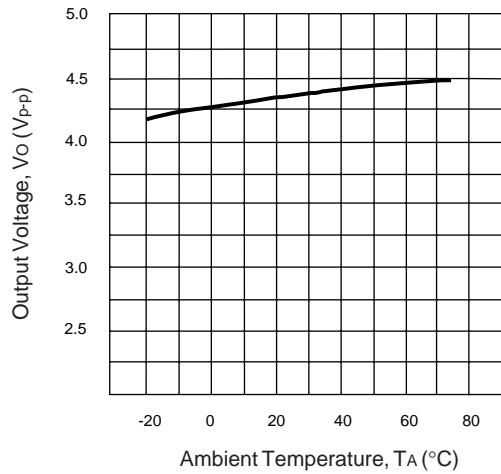
* See Application Circuit

TYPICAL PERFORMANCE CURVES (T_A = 25°C)

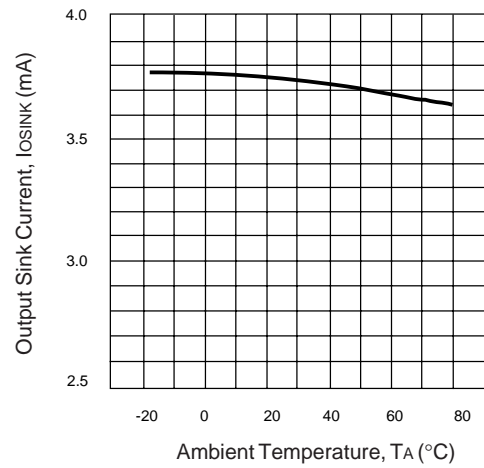


TYPICAL PERFORMANCE CURVES ($T_A = 25^\circ\text{C}$)

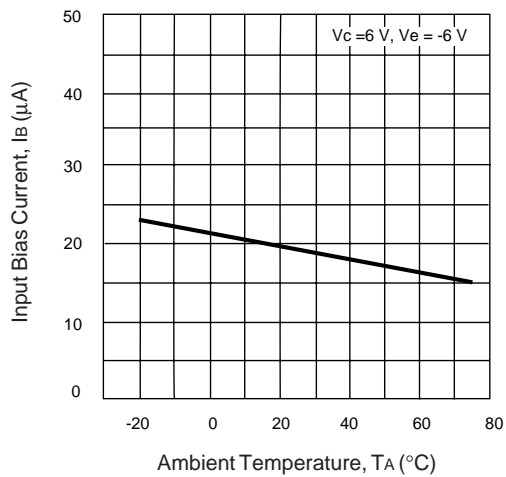
**SINGLE ENDED OUTPUT VOLTAGE
SWING vs. TEMPERATURE**



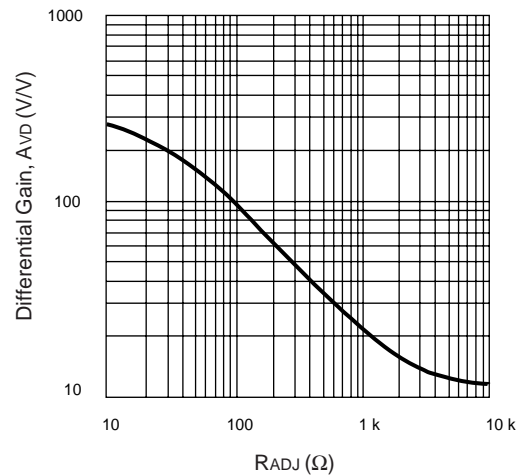
SINK CURRENT vs. TEMPERATURE



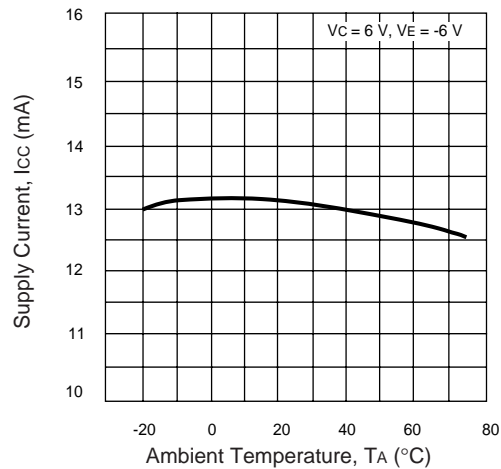
**INPUT BIAS CURRENT
vs. TEMPERATURE**



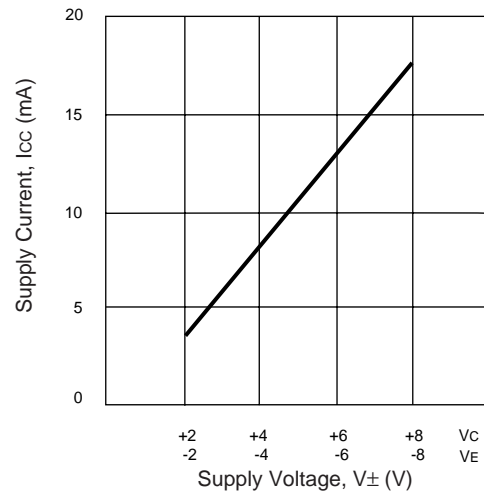
**DIFFERENTIAL VOLTAGE GAIN vs.
RESISTANCE BETWEEN G_A AND G_B**



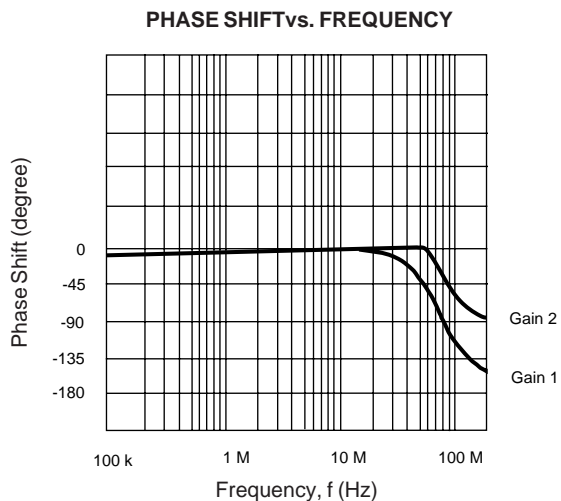
SUPPLY CURRENT vs. TEMPERATURE



SUPPLY CURRENT vs. SUPPLY VOLTAGE

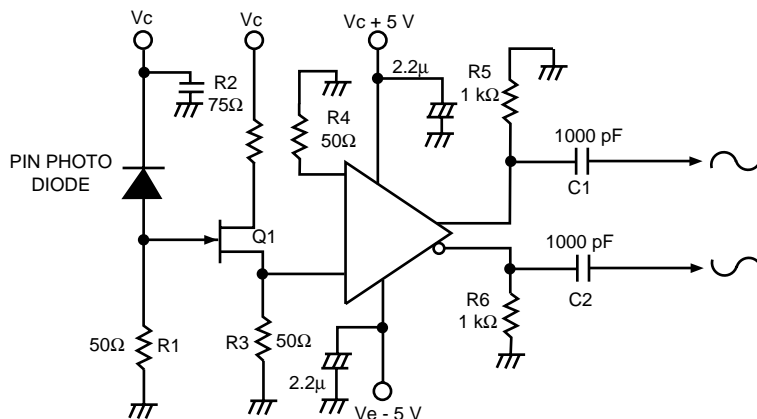


TYPICAL PERFORMANCE CURVES (T_A = 25°C)



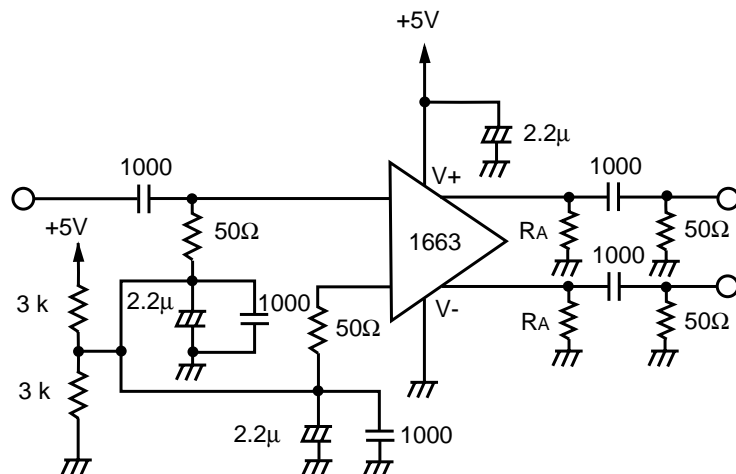
TYPICAL APPLICATIONS

• Photo Signal Detector

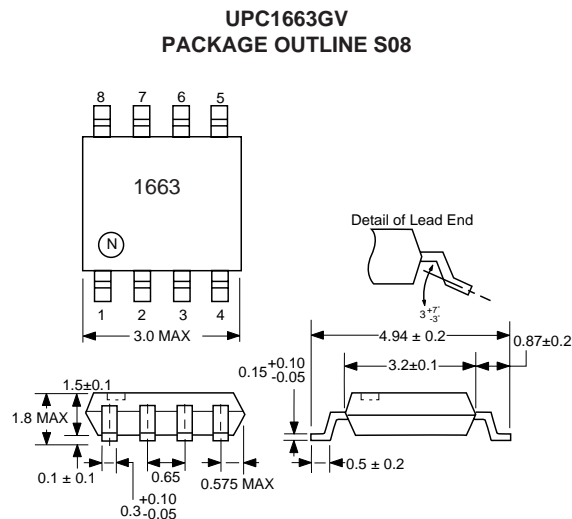
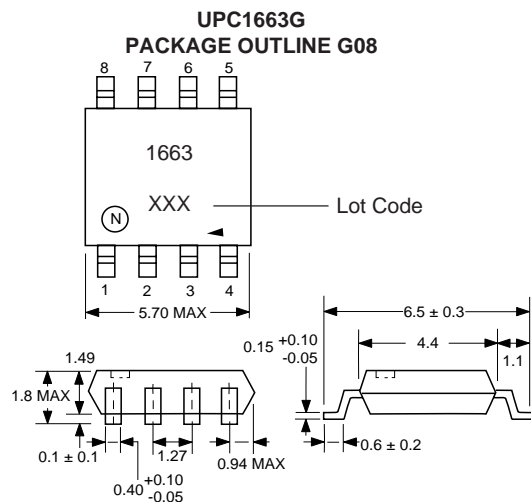


Since the input impedance of the IC falls when the gain rises, stable operation can be achieved by inserting a FET buffer when necessary as illustrated above.

• Application for +5 V Single Supply



OUTLINE DIMENSIONS (Units in mm)



Notes:

- Each lead centerline is located within 0.12 mm (0.005 inch) of its true position at maximum material condition.
- All dimensions are typical unless otherwise specified.

CONNECTION DIAGRAM (TOP VIEW)

ORDERING INFORMATION

PART NUMBER	QUANTITY
UPC1663G-E1	2500/Reel
UPC1663GV-E1	1000/Reel

